

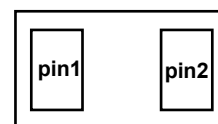
## Description

- ◆ This low-power TVS (Transient Voltage Suppressor) is mainly used for signal and power supply to protect the back-stage circuit from ESD(Electrostatic Discharge) and EFT(Electrical Fast Transients) and improve the reliability of the product, because its extremely small package is suitable for various portable devices and mobile electronic devices.



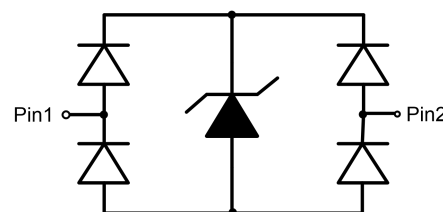
## Features

- ◆ IEC61000-4-2(ESD):±20KV Max Air  
±15KV Max Contact
- ◆ IEC61000-4-4(EFT):40A(5/50ns)
- ◆ IEC61000-4-5(Surge):5A (8/20us)
- ◆ Line capacitance: 0.5pF(typical)@1MHz
- ◆ Very low reverse current:  $I_R < 0.5\mu A$ (typical)
- ◆ Halogen free ,Lead free and RoHs



## Application

- ◆ Cellular phones
- ◆ Portable devices
- ◆ Digital cameras
- ◆ Player
- ◆ Smart home
- ◆ Robot



**Circuit Diagram**

## Order information

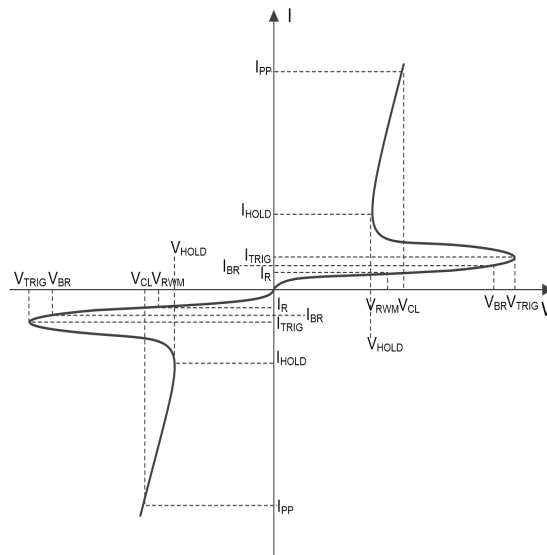
| Model      | Marking | Package    | shipping        |
|------------|---------|------------|-----------------|
| ESD5D005LA | S1      | DFN1006-2L | 10000/Tape&Reel |

## Electrical characteristic(T=25°C, unless otherwise specified)

| Parameter                 | Symbol    | Conditions                 | Min. | TYP. | Max.      | Units   |
|---------------------------|-----------|----------------------------|------|------|-----------|---------|
| Reverse stand-off voltage | $V_{RWM}$ |                            |      |      | $\pm 5.0$ | V       |
| Reverse leakage current   | $I_R$     | $V_{RWM}=5.0V$             |      |      | 0.5       | $\mu A$ |
| Reveres breakdown voltage | $V_B$     | $I_T=1mA$                  | 6.5  | 8.5  |           | V       |
| Reveres holding voltage   | $V_h$     | $I_h=100mA$                | 2.6  |      | 4.0       | V       |
| Dynamic resistance        | $R_{DYN}$ | $T_p=10/100ns$             |      | 0.23 |           |         |
| Clamping voltage          | $V_C$     | $I_{PP}=1A, t_p=8/20\mu s$ |      | 5.0  |           | V       |
|                           |           | $I_{pp}=5A, t_p=8/20\mu s$ |      | 6.0  | 8.0       | V       |
| Junction capacitance      | $C_J$     | $V_R=0V f=1MHz$            |      | 0.5  | 0.7       | pF      |
|                           |           | $V_R=0V f=1GHz$            |      | 0.3  |           | pF      |

## Electrical characteristic(T=25°C, unless otherwise specified)

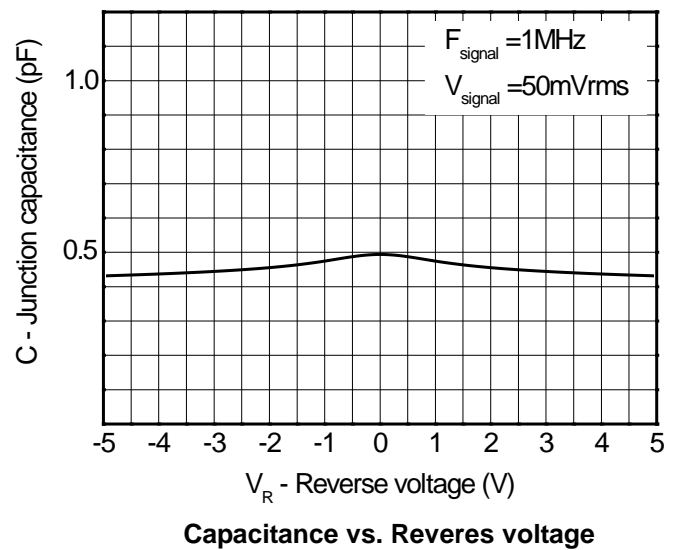
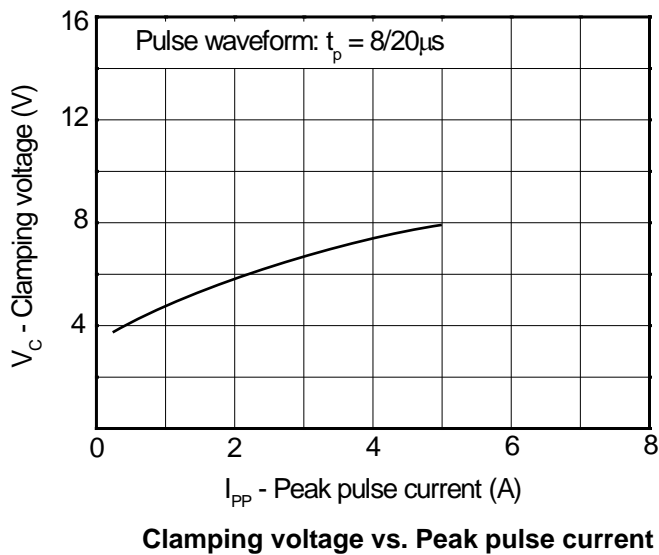
- $V_{RWM}$  Reverse stand-off voltage
- $I_R$  Reverse leakage current
- $V_{CL}$  Clamping voltage
- $I_{PP}$  Peak pulse current
- $V_{TRIG}$  Reverse trigger voltage
- $I_{TRIG}$  Reverse trigger current
- $V_{BR}$  Reverse breakdown voltage
- $I_{BR}$  Reverse breakdown current
- $V_{HOLD}$  Reverse holding voltage
- $I_{HOLD}$  Reverse holding current

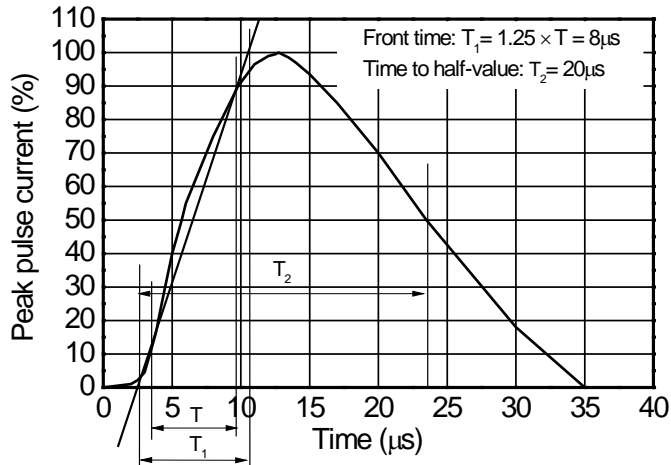


## Maximum Rating

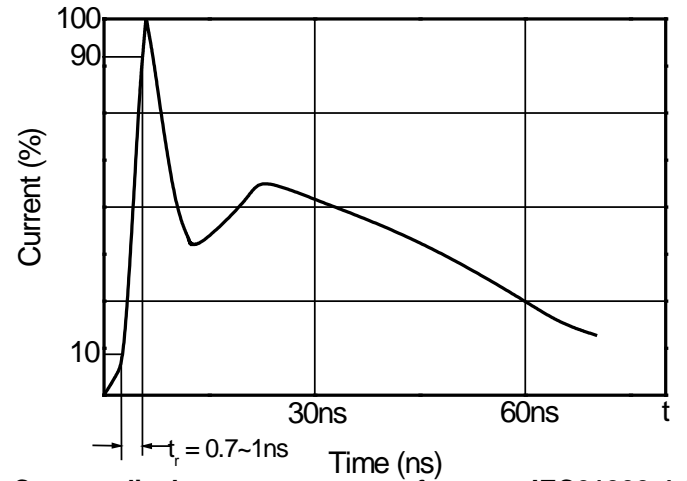
| Rating                                | symbol    | value    | Units       |
|---------------------------------------|-----------|----------|-------------|
| Peak Pulse Current( $t_p=8/20\mu s$ ) | $I_{pp}$  | 5.0      | A           |
| ESD per IEC61000-4-2(Contact)         | $V_{ESD}$ | $\pm 15$ | KV          |
| ESD per IEC61000-4-2(Air)             |           | $\pm 20$ |             |
| Operating Temperature                 | $T_J$     | -40~85   | $^{\circ}C$ |
| Storage Temperature                   | $T_{STG}$ | -55~155  | $^{\circ}C$ |

## Typical characteristic

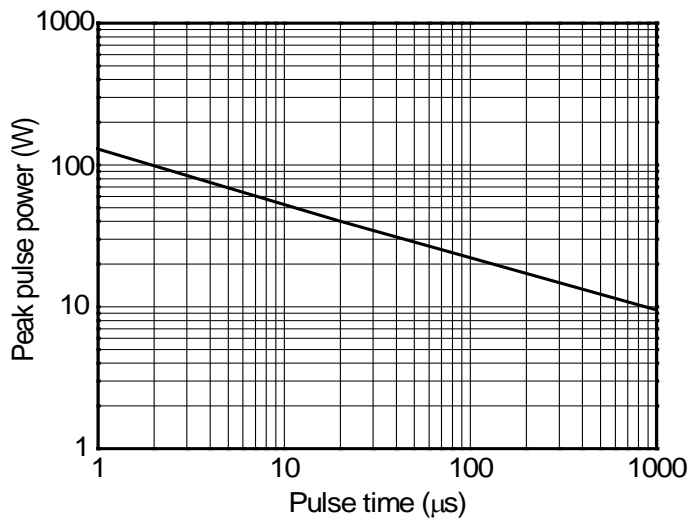




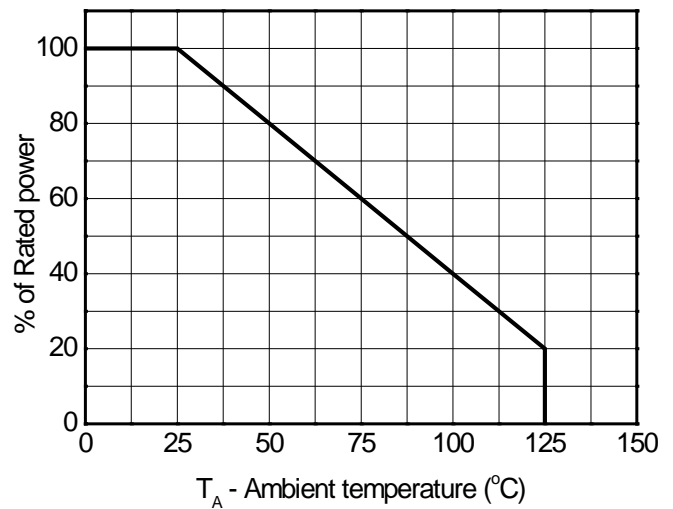
8/20μs waveform per IEC61000-4-5



Contact discharge current waveform per IEC61000-4-2



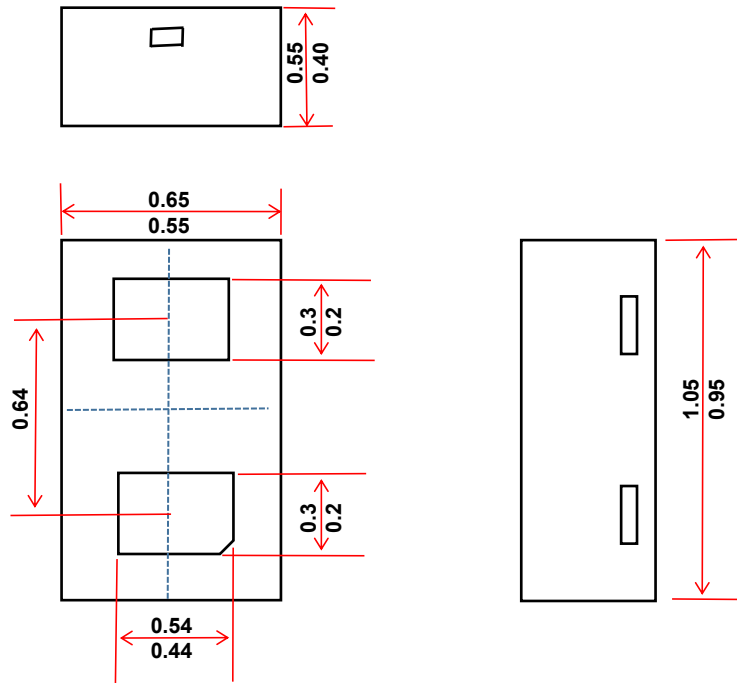
Non-repetitive peak pulse power vs. Pulse time



Power derating vs. Ambient temperature

**Dimension outline** Unit:mm

**DFN1006-2L(SOD882)**



**Recommended Mounting Pad Layout** Unit:mm

